NSN 5961-00-813-9029

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Inclosure Material:

Metal

Overall Length:

0.520 inches

Overall Diameter:

1.250 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Thread Size:

0.190 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

400.0 collector to emitter voltage, dc and -5.0 emitter to base voltage, dc

Power Rating Per Characteristic:

150.0 watts total power dissipation

Special Features:

Junction pattern arrangement: npn

Test Data Document:

18876-mis17247 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Thread Series Designator:

Unf

Terminal Type And Quantity:

1 threaded stud and 2 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0